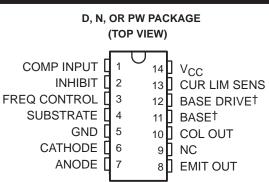
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- High Efficiency . . . 60% or Greater
- Output Current . . . 500 mA
- Input Current Limit Protection
- TTL-Compatible Inhibit
- Adjustable Output Voltage
- Input Regulation . . . 0.2% Typ
- Output Regulation . . . 0.4% Typ
- Soft Start-Up Capability

description

The TL497A incorporates all the active functions required in the construction of switching voltage regulators. It can also be used as the control



NC - No internal connection

[†] BASE (11) and BASE DRIVE (12) are used for device testing only. They normally are not used in circuit applications of the device.

element to drive external components for high-power-output applications. The TL497A was designed for ease of use in step-up, step-down, or voltage-inversion applications requiring high efficiency.

The TL497A is a fixed-on-time variable-frequency switching-voltage-regulator control circuit. The switch-on time is programmed by a single external capacitor connected between FREQ CONTROL and GND. This capacitor, C_T , is charged by an internal constant-current generator to a predetermined threshold. The charging current and the threshold vary proportionally with V_{CC}. Thus, the switch-on time remains constant over the specified range of input voltage (4.5 V to 12 V). Typical on times for various values of C_T are as follows:

TIMING CAPACITOR, CT (pF)	200	250	350	400	500	750	1000	1500	2000
ON TIME (µs)	19	22	26	32	44	56	80	120	180

The output voltage is controlled by an external resistor ladder network (R1 and R2 in Figures 1, 2, and 3) that provides a feedback voltage to the comparator input. This feedback voltage is compared to the reference voltage of 1.2 V (relative to SUBSTRATE) by the high-gain comparator. When the output voltage decays below the value required to maintain 1.2 V at the comparator input, the comparator enables the oscillator circuit, which charges and discharges C_T as described above. The internal pass transistor is driven on during the charging of C_T . The internal transistor can be used directly for switching currents up to 500 mA. Its collector and emitter are uncommitted, and it is current driven to allow operation from the positive supply voltage or ground. An internal Schottky diode matched to the current characteristics of the internal transistor also is available for blocking or commutating purposes. The TL497A also has on-chip current-limit circuitry that senses the peak currents in the switching regulator and protects the inductor against saturation and the pass transistor against overstress. The current limit is adjustable and is programmed by a single sense resistor, R_{CL} , connected between V_{CC} and CUR LIM SENS. The current-limit circuitry is activated when 0.7 V is developed across R_{CL} .

Simplicity of design is a primary feature of the TL497A. With only six external components (three resistors, two capacitors, and one inductor), the TL497A operates in numerous voltage-conversion applications (step-up, step-down, invert) with as much as 85% of the source power delivered to the load. The TL497A replaces the TL497 in all applications.

The TL497AC is characterized for operation from 0°C to 70°C. The TL497AI is characterized for operation from –40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



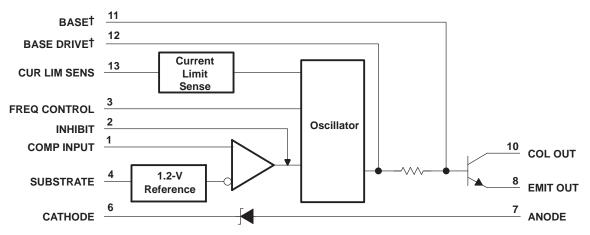
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AVAILABLE OPTIONS								
	CHIP							
TA	SMALL-OUTLINE (D)	PLASTIC DIP (N)	SHRINK SMALL-OUTLINE (PW)	FORM (Y)				
0°C to 70°C	TL497ACD	TL497ACN	TL497ACPW	TL497AY				
–40°C to 85°C	TL497AID	TL497AIN	—	—				

The D and PW packages are only taped and reeled. Add the suffix R to the device type (e.g., TL497ACPWR). Chip forms are tested at 25° C.

functional block diagram



[†] BASE and BASE DRIVE are used for device testing only. They normally are not used in circuit applications of the device.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V _{CC} (see Note 1) Output voltage, V _O Input voltage, V _I (COMP INPUT) Input voltage, V _I (INHIBIT) Diode reverse voltage Power switch current	
Diode forward current Package thermal impedance, θ_{IA} (see Notes 2 and 3):	
	N package
Lead temperature 1,6 mm (1/16 inch) from case for 60 s Storage temperature range, T_{stg}	

[†]Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values except diode voltages are with respect to network ground terminal.

- 2. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can impact reliability.
- 3. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions

			MIN	MAX	UNIT
Supply voltage, V _{CC}	4.5	12	V		
High-level input voltage, VIH	INHIBIT pin	2.5		V	
Low-level input voltage, VIL	INHIBIT pin	INHIBIT pin			
Output voltage	Step-up configuration (see Figure 1)	Step-up configuration (see Figure 1)			
	Step-down configuration (see Figure 2)	Vref	Vj – 1	V	
	Inverting regulator (see Figure 3)			-25	
Power switch current					mA
Diode forward current					mA
Operating free-air temperature range, T _A		0	70	°C	
	TL497AI		-40	85	0



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electrical characteristics over recommended operating conditions, $V_{CC} = 6 V$ (unless otherwise noted)

	TEST CONDITIONS		т _А †	TL497AC			TL497AI				
PARAMETER				MIN	TYP‡	MAX	MIN	TYP‡	MAX	UNIT	
High-level input current, INHIBIT	V _{I(I)} = 5 V	V _{I(I)} = 5 V			0.8	1.5		0.8	1.5	mA	
Low-level input current, INHIBIT	$V_{I(I)} = 0 V$		Full range		5	10		5	20	μΑ	
Comparator reference voltage	V _I = 4.5 V to	06 V	Full range	1.08	1.2	1.32	1.14	1.2	1.26	V	
Comparator input bias current	V _I = 6 V		Full range		40	100		40	100	μΑ	
Switch on-state voltage		I _O = 100 mA	25°C		0.13	0.2		0.13	0.2	v	
	V _I = 4.5 V	I _O = 500 mA	Full range			0.85			1		
Switch off-state current	$V_{I} = 4.5 V, V_{O} = 30 V$	V _O = 30 V	25°C		10	50		10	50	u A	
			Full range			200			500		
Sense voltage, CUR LIM SENS	VI = 6 V		25°C	0.45		1	0.45		1	V	
Diode forward voltage	I _O = 10 mA I _O = 100 mA		Full range		0.75	0.85		0.75	0.95	v	
			Full range		0.9	1		0.9	1.1		
	I _O = 500 mA	Ą	Full range		1.33	1.55		1.33	1.75	5	
Diode reverse voltage	I _O = 500 μA		Full range				30			v	
	l _O = 200 μA	L	Full range	30							
On state supply surrent					11	14		11	14	mA	
On-state supply current			Full range			15			16		
			25°C		6	9		6	9	mA	
Off-state supply current			Full range			10			11		

[†] Full range is 0°C to 70°C for the TL497AC and -40°C to 85°C for the TL497AI.

[‡] All typical values are at $T_A = 25^{\circ}C$.

electrical characteristics over recommended operating conditions, V_{CC} = 6 V, T_A = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TL497AY	UNIT	
PARAMETER	TEST CONDITIONS	MIN TYP MAX		
High-level input current, INHIBIT	$V_{I(I)} = 5 V$	0.8	mA	
Low-level input current, INHIBIT	$V_{I(I)} = 0 V$	5	μΑ	
Comparator reference voltage	$V_{I} = 4.5 V$ to 6 V	1.2	V	
Comparator input bias current	$V_{I} = 6 V$	40	μΑ	
Switch on-state voltage	$V_{I} = 4.5 V$, $I_{O} = 100 mA$	0.13	V	
Switch off-state current	$V_{I} = 4.5 V$, $V_{O} = 30 V$	10	μΑ	
	I _O = 10 mA	0.75		
Diode forward voltage	I _O = 100 mA	0.9	V	
	I _O = 500 mA	1.33		
On-state supply current		11	mA	
Off-state supply current		6	mA	



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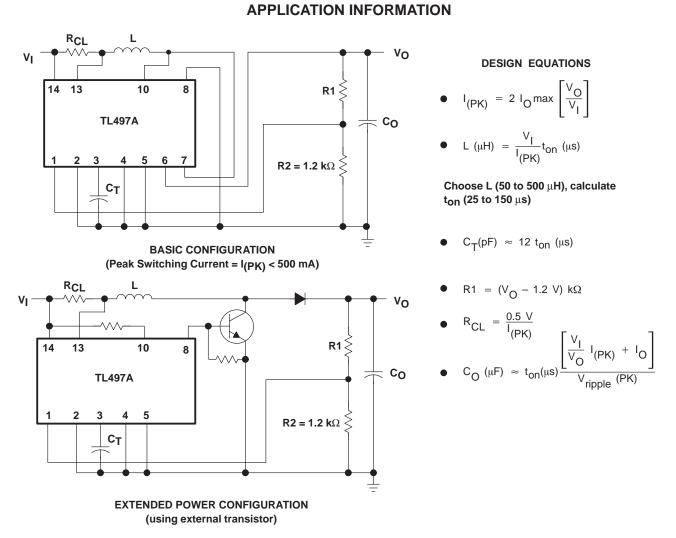


Figure 1. Positive Regulator, Step-Up Configurations



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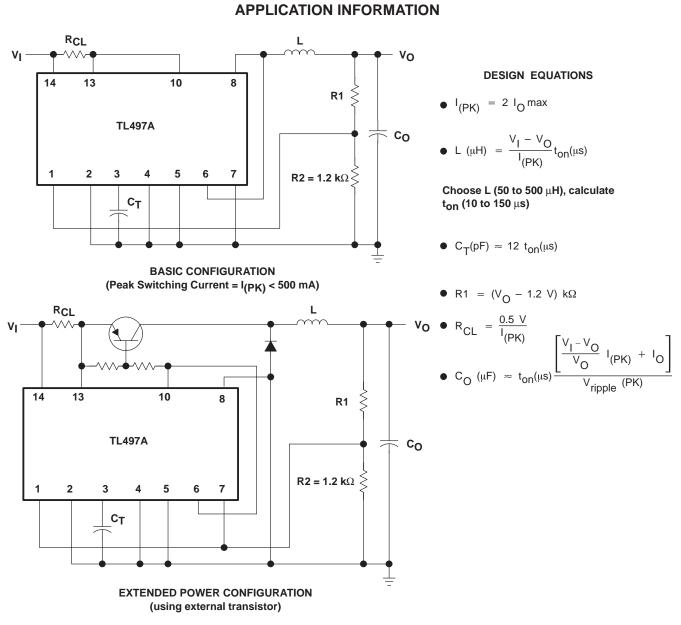
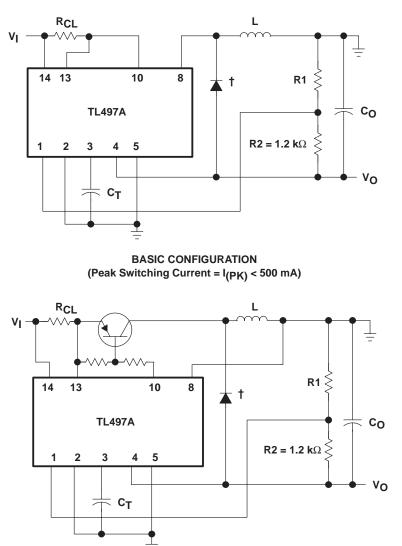


Figure 2. Positive Regulator, Step-Down Configurations



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EXTENDED POWER CONFIGURATION (using external transistor)

[†] Use external catch diode, e.g., 1N4001, when building an inverting supply with the TL497A.

Figure 3. Inverting Applications



•
$$I_{(PK)} = 2 I_0 \max \left[1 + \frac{|V_0|}{V_1} \right]$$

• L (
$$\mu$$
H) = $\frac{V_{I}}{I_{(PK)}}t_{on}(\mu s)$

Choose L (50 to 500 $\mu\text{H}),$ calculate t_{on} (10 to 150 $\mu\text{s})$

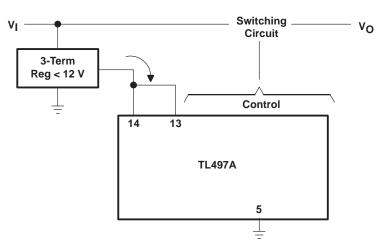
• $C_T(pF) \approx 12 t_{on}(\mu s)$

• R1 =
$$(|V_0| - 1.2 V) k\Omega$$

$$R_{CL} = \frac{0.5 \text{ V}}{I(PK)} \left[\frac{|V_{I}|}{|V_{O}|} I(PK) + I_{O} \right]$$

• $C_{O} (\mu F) \approx t_{ON}(\mu s) \frac{\left[\frac{|V_{I}|}{|V_{O}|} I(PK) + I_{O} \right]}{V_{ripple} (PK)}$

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APPLICATION INFORMATION

EXTENDED INPUT CONFIGURATION WITHOUT CURRENT LIMIT

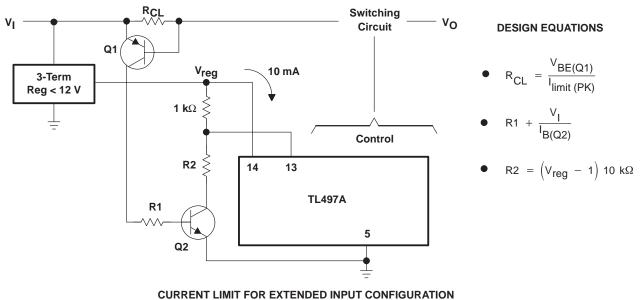


Figure 4. Extended Input Voltage Range ($V_I > 12 V$)



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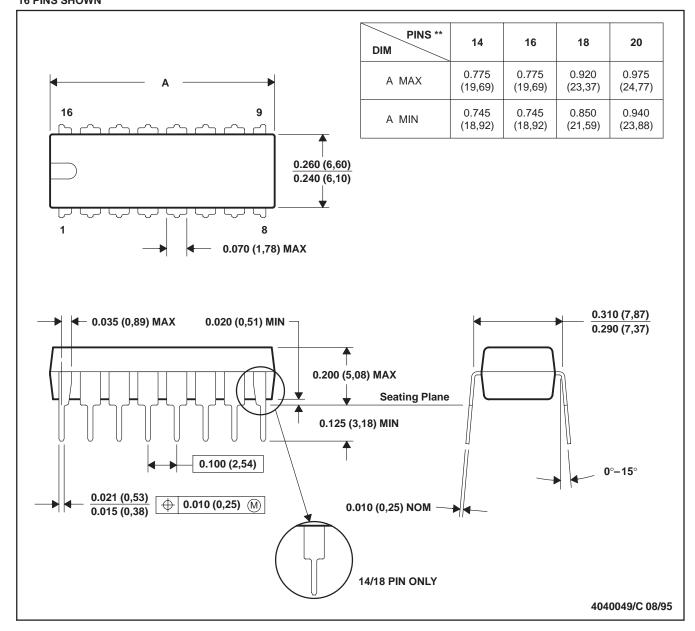
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MECHANICAL DATA

MPDI002A - JANUARY 1995 - REVISED OCTOBER 1995

PLASTIC DUAL-IN-LINE PACKAGE

N (R-PDIP-T**) 16 PINS SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Falls within JEDEC MS-001 (20-pin package is shorter than MS-001).

